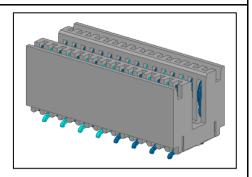


#### MODEL DESCRIPTION

This is an s-parameter model for DDR4 vertical through-hole DIMM connector without PCB effects.



#### APPLICABLE SERIES NUMBER:

78726

MODEL FILENAME: SP-78726-004_RevA.s24p	MODEL FORMAT: Touchstone (*.sNp)
MODEL TYPE: S-parameter	DATA FORMAT: Magnitude/Phase
MODEL BASIS: Analytical 3D Field Solution	MODEL SOURCE: Ansys HFSS ver. 15.0.0
BANDWIDTH: DC – 15 GHz	RESOLUTION: 10 MHz Steps
REFERENCE: 50 ohms	<b>NUMBER OF POINTS:</b> 1501 (1500 + 1 DC)
NUMBER OF PORTS: 24 Single-Ended	VALIDATION: No

**DISCLAIMERS:** Information contained in this document is simulated. Molex Incorporated does not guarantee the performance of the final product to the information provided in this document.

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The user is responsible for verifying the results of their use of this information, and assumes all risk of doing or not doing so. Use of the electronic file evidences user's agreement to the above terms.

Any charts or schematics in this report are only for general reference. The schematic allows the user to configure a similar simulation circuit in any simulation tool. The resulting charts provided allow a comparison of results to the Molex simulation using the stated schematic.

REVISION:	<u>ECN INFORMATION:</u> <u>EC No:</u> <b>\$2015-0773</b>	TITLE: 0.85mm Pitch DDR4 Vertical Through-Hole DIMM Connector		1 of <b>7</b>	
Α	DATE: <b>2015/01/11</b>	MC	1 01 7		
DOCUMENT NUMBER:		CREATED / REVISED BY:	CHECKED BY:	APPRO\	/ED BY:
EE-78726-004		CMWONG 2015/01/12	WHFOO 2015/01/12	WTCHUA 2	2015/01/12

TEMPLATE FILENAME: SPM[SIZE\_A](V.1).DOC



## TERMINAL TO MODEL PORT MAPPING TABLE

#### **AVAILABLE MODEL SIGNAL PATHS**

TERMINAL	INPUT PORT (MAIN BOARD ATTACHMENT SIDE)	DESCRIPTION	OUTPUT PORT (MODULE BOARD MATING SIDE)	DESCRIPTION
Front Side Outer Row P2	1	in_F1	13	out_F1
Front Side Outer Row P4	2	in_F2	14	out_F2
Front Side Outer Row P6	3	in_F3	15	out_F3
Front Side Outer Row P8	4	in_F4	16	out_F4
Front Side Inner Row P9	5	in_F5	17	out_F5
Front Side Inner Row P11	6	in_F6	18	out_F6
Front Side Inner Row P13	7	in_F7	19	out_F7
Front Side Inner Row P15	8	in_F8	20	out_F8
Back Side Inner Row P150	9	in_B1	21	out_B1
Back Side Inner Row P152	10	in_B2	22	out_B2
Back Side Inner Row P154	11	in_B3	23	out_B3
Back Side Inner Row P156	12	in_B4	24	out_B4

### **PRE-DEFINED MODEL RETURN PATHS**

TERMINAL	DESCRIPTION
Front Side Inner Row P1	G
Front Side Inner Row P3	G
Front Side Inner Row P5	G
Front Side Inner Row P7	G
Front Side Outer Row P10	G
Front Side Outer Row P12	G
Front Side Outer Row P14	G
Front Side Outer Row P16	G

TERMINAL	DESCRIPTION
Back Side Outer Row P143	G
Back Side Inner Row P144	G
Back Side Outer Row P145	G
Back Side Inner Row P146	G
Back Side Outer Row P147	G
Back Side Inner Row P148	G
Back Side Outer Row P149	G
Back Side Outer Row P151	G
Back Side Outer Row P153	G
Back Side Outer Row P155	G
Back Side Outer Row P157	G
Back Side Inner Row P158	G

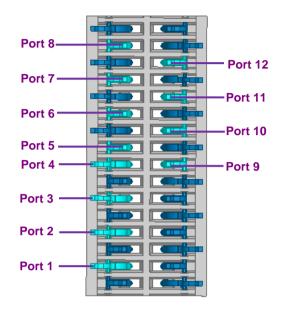
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A	DATE: <b>2015/01/11</b>	MC	DLEX CONFIDENTIAL	<b>2</b> of <b>7</b>	
DOCUMEN <sup>*</sup>	UMENT NUMBER: <u>CREATED / REVISED BY:</u> <u>CHECKED BY:</u> <u>APPRO</u>		/ED BY:		
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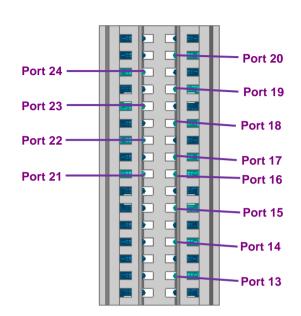


### **PART ILLUSTRATIONS**

## **Connector (Bottom View)**

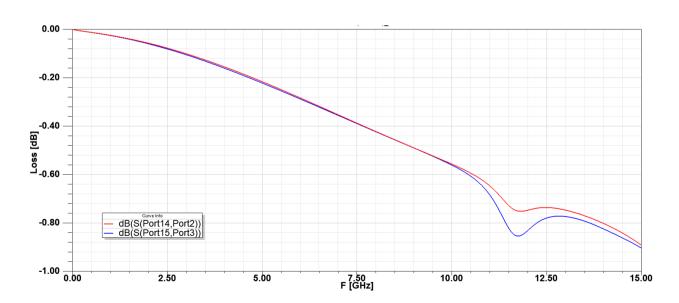


## **Connector (Top View)**



### **REFERENCE RESULTS**

**Frequency Domain: Insertion Loss** 



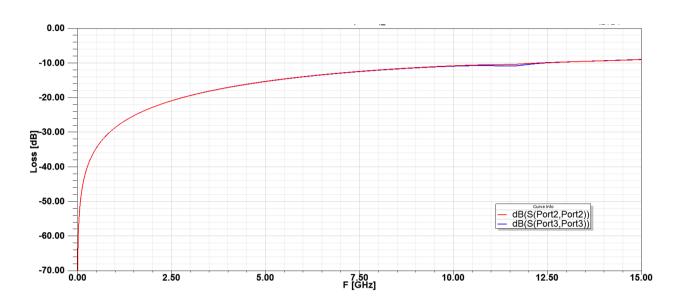
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Α	EC No: <b>S2015-0773</b>	Connector		3 of 7	
A	DATE: <b>2015/01/11</b>	МС	MOLEX CONFIDENTIAL		
DOCUMENT NUMBER:		CREATED / REVISED BY:	CHECKED BY:	APPRO\	/ED BY:
EE-78726-004		CMWONG 2015/01/12	WHFOO 2015/01/12	WTCHUA 2	2015/01/12

TEMPLATE FILENAME: SPM[SIZE\_A](V.1).DOC



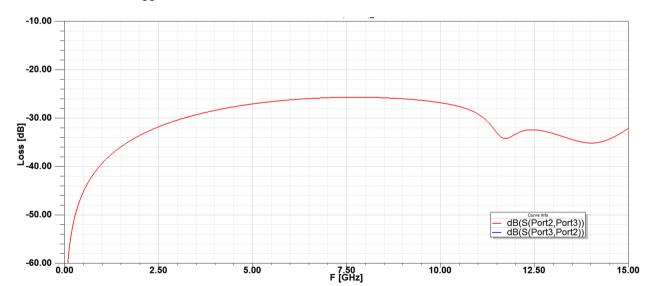
### **REFERENCE RESULTS**

Frequency Domain: Return Loss



## Frequency Domain: Near End Crosstalk

- 1:1 S/G ratio
- Both victim and aggressor located at outer row



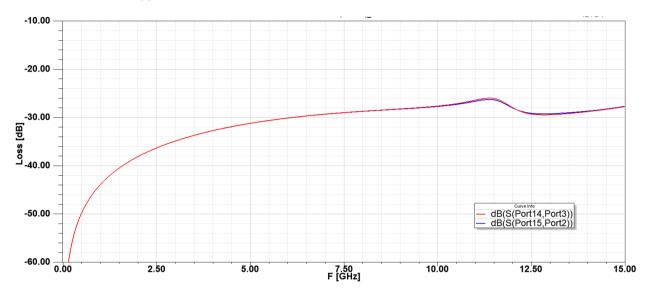
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Α	EC No: <b>S2015-0773</b> DATE: <b>2015/01/11</b>			<b>4</b> of <b>7</b>	
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### **REFERENCE RESULTS**

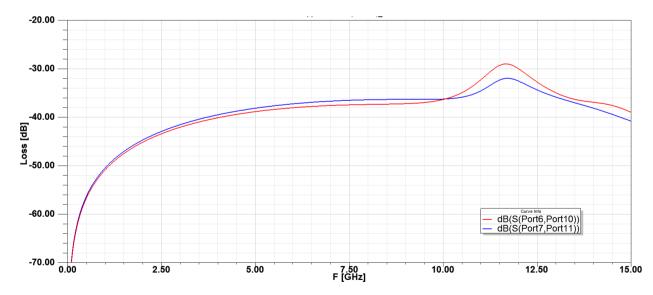
## Frequency Domain: Far End Crosstalk

- 1:1 S/G ratio
- Both victim and aggressor located at outer row



### Frequency Domain: Near End Crosstalk

- 1:1 S/G ratio
- Victim locates at inner row from front side
- Aggressor locates at inner row from back side.



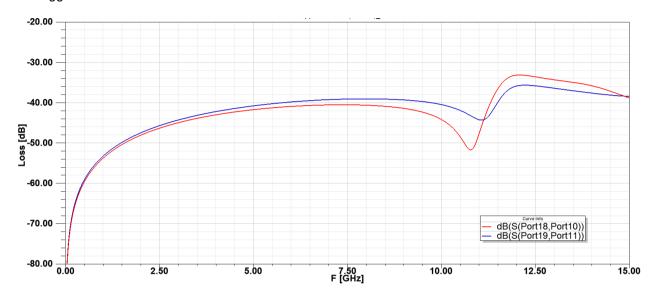
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A	EC No: <b>\$2015-0773</b>	Connector		F . 7
DATE: 2015/01/11		MOLEX CONFIDENTIAL		<b>5</b> of <b>7</b>
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E	EE-78726-004 CMWONG 2015/01/12 WHFOO 2015/01/12 WTCHUA 2		2015/01/12	
TEMPLATE FILENAME: SPM[SIZE_A](V.1).DOC				



### **REFERENCE RESULTS**

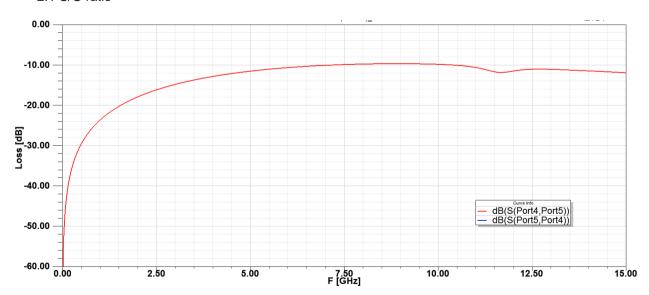
## Frequency Domain: Far End Crosstalk

- 1:1 S/G ratio
- Victim locates at inner row from front side
- Aggressor locates at inner row from back side.



## Frequency Domain: Near End Crosstalk

2:1 S/G ratio



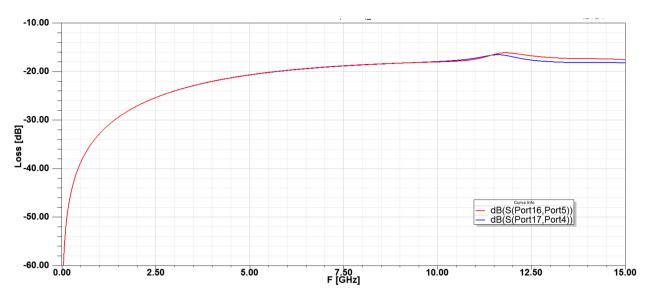
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Α	EC No: <b>S2015-0773</b>	Connector		<b>6</b> of <b>7</b>	
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### **REFERENCE RESULTS**

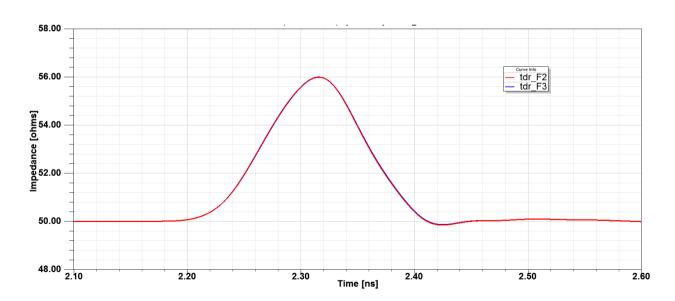
## Frequency Domain: Far End Crosstalk

2:1 S/G ratio



## **Time Domain: TDR Impedance**

Rise-time of 100ps [10%~90%] at connector launch



TEMPLATE FILENAME: SPM[SIZE_A](V.1).DOC					
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DOCUMENT NUMBER:		CREATED / REVISED BY:	CHECKED BY:	APPRO\	VED BY:
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Α	EC No: <b>S2015-0773</b>	Connector			<b>7</b> of <b>7</b>
REVISION:	ECN INFORMATION:	TITLE: 0.85mm Pitch DDR4 Vertical Through-Hole DIMM		SHEET No.	